1765

PTO/SB/21 (01-03) Approved for use through 04/30/2003. OMB 0651-0031
U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it displays a valid OMB control number Application Number 10/065.551 TRANSMITTAL Filing Date 10/29/2002 **FORM** First Named Inventor Roman Chistyakov Art Unit 1765 (to be used for all correspondence after initial filing) Examiner Name Nguyen (Also, copies of cited references) Total Number of Pages in This Submission Attorney Docket Number ZON-004 **ENCLOSURES** (Check all that apply) After Allowance Communication to Group Fee Transmittal Form Drawing(s) Appeal Communication to Board Licensing-related Papers of Appeals and Interferences Fee Attached Appeal Communication to Group Petition (Appeal Notice, Brief, Reply Brief) Amendment/Reply Petition to Convert to a Proprietary Information After Final Provisional Application Power of Attorney, Revocation Status Letter Affidavits/declaration(s) Change of Correspondence Address Other Enclosure(s) (please Terminal Disclaimer Identify below): Extension of Time Request PTO Form 1449 (3 pgs.); References B1-B2 and C1-C12; Request for Refund Express Abandonment Request and Return Receipt Postcard. CD, Number of CD(s) Information Disclosure Statement Remarks Certified Copy of Priority Document(s) Response to Missing Parts/ Incomplete Application Response to Missing Parts under 37 CFR 1.52 or 1.53 SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT Firm Kurt Rauschenbach Individual Signature Date July 2, 2003 CERTIFICATE OF TRANSMISSION/MAILING I hereby certify that this correspondence is being facsimile transmitted to the USPTO or deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, Washington, DC 20231 on this date: July 2, 2003 Typed or printed Kurt Rauschenbach

This collection of information is required by 37 CFR 1.5. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 12 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, Washington, DC 20231. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. **SEND TO:** Commissioner for Patents, Washington, DC 20231.

Signature

July 2, 2003

Date



PATENT Attorney Docket No. ZON-004

10 100 mg

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT(S):

Roman Chistyakov

SERIAL NO.:

10/065,551

GROUP NO.:

1765

FILING DATE:

October 29, 2002

EXAMINER:

Duy Vu Nguyen

TITLE:

HIGH POWER PULSED MAGNETICALLY ENHANCED PLASMA

PROCESSING

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. BOX 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. §1.97, Applicants hereby make of record the references listed on the accompanying Form PTO-1449 for consideration by the Examiner in connection with the examination of the above-identified patent application. Copies of the references are enclosed.

REMARKS

In accordance with the provisions of 37 C.F.R. §1.97, this statement is being filed (CHECK ONE):

(1)	within three (3) months of the Filing Date or before the mailing date of the First Office Action on the merits; or
(2)	after the period defined in (1) but before the mailing date of a Final Rejection or Notice of Allowance , and
	the requisite Statement is below, OR
	the requisite fee under Rule 1.17(p), namely \$180.00, is included herein, or
(3)	after the mailing date of a Final Rejection or Notice of Allowance but before the payment of the Issue Fee . AND
	Applicant hereby Petitions the Commissioner to accept and consider the attached Information Disclosure Statement, AND
	the requisite Statement is below, AND
	the requisite petition fee due under Rule 1.17(i)(I), namely \$130.00 is included herein.

Information Disclosure Statement

Serial No.: 10/065,551

Page 2 of 2

It is respectfully requested that each of the references shown on the attached Form PTO-1449 be made of record in this application.

STATEMENT

As required under §1.97(e), Applicants, through the undersigned, hereby state either that [check the appropriate space]:

- 1. [E]ach item of information contained in the Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application **not more than** three months prior to the filing date of the Information Disclosure Statement; or
 - 2. [N]o item of information contained in the Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application, and to the knowledge of the person signing this Statement after making reasonable inquiry, no item of information contained in the Information Disclosure Statement was known to any individual designated in §1.56(c) more than three months prior to the filing of the Information Disclosure Statement.

FEE AUTHORIZATION

Should any fee associated with the submission of this paper not be attached hereto as a check, the Commissioner is authorized to charge the missing fee to our Deposit Account, No. 501211. Any overpayments should be credited to said Deposit Account.

Respectfully submitted,

Date: July 2, 2003 Reg. No. 40,137

Tel. No.: (781) 271-1503 Fax No.: (781) 271-1527 Kurt Rauschenbach

Atty/Agent for Applicant(s)
Rauschenbach Patent Law Group, LLC

Post Office Box 387 Bedford, MA 01730 PTO/SB/08B (10-01)
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Substitute for form	1449B/PTO			Complete if Known			
			01 001105	Application Number	10/065,551		
IINFORMA	ATION	DIS	CLOSURE	Filing Date	10/29/2002		
STATEM	ENT RY	γ ΔΙ	PPLICANT	First Named Inventor	Chistyakov		
		· ^:	LIOAIII	Group Art Unit	1765		
(use	as many she	ets as	necessary)	Examiner Name	Nguyen		
Sheet	3	of	3	Attorney Docket Number	ZON-004		

OTHER PRIOR ART NON PATENT LITERATURE DOCUMENTS						
Examiner nitials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	1			
	С9	MOZGRIN, ET AL., High-Current Low-Pressure Quasi -Stationary Discharge In A Magnetic Field: Experimental Research, Plasma Physics Reports, 1995, Pgs. 400-409, Vol. 21, No. 5, Mozgrin, Feitsov, Khodachenko.				
	C10	ROSSNAGEL, ET AL., Induced Drift Currents In Circular Planar Magnetrons, J. Vac. Sci. Technol. A., January/February 1987, Pgs. 88-91, Vol. 5, No. 1, American Vacuum Society.				
	CH	SHERIDAN, ET AL., Electron Velocity Distribution Functions In A Sputtering Magnetron Discharge For The EXB Direction, J. Vac. Sci. Technol. A., July/August 1998, Pgs. 2173-2176, Vol. 16, No. 4, American Vacuum Society.]			
and the second s	C12	STEINBRUCHEL, A Simple Formula For Low-Energy Sputtering Yields, Applied Physics A., 1985, Pgs. 37-42, Vol. 36, Springer-Verlag.				
						

Examiner	Date	
Signature	Considered	

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Complete if Known							
Application Number 10/065,551							
Filing Date	10/29/2002						
First Named Inventor	Chistyakov 🔾						
Group Art Unit	1765						
Examiner Name	Nguyen						
Attorney Docket Number	ZON-004						

		OTHER PRIOR ART NON PATENT LITERATURE DOCUMENTS	
Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	
	C1	BOOTH, ET AL., The Transition From Symmetric To Asymmetric Discharges In Pulsed 13.56 MHz Capacity Coupled Plasmas, J. Appl. Phys., July 15, 1997, Pgs. 552-560, Vol. 82 (2), American Institute of Physics.	
	C2	BUNSHAH, ET AL., Deposition Technologies For Films And Coatings, Materials Science Series, Pgs. 176-183, Noyes Publications, Park Ridge, New Jersey.	
	C3	DAUGHERTY, ET AL., Attachment-Dominated Electron-Beam-Ionized Discharges, Applied Science Letters, May 15, 1976, Vol. 28, No. 10, American Institute of Physics.	
grander algorithma (n. 1922).	C4	GOTO, ET AL., Dual Excitation Reactive Ion Etcher for Low Energy Plasma Processing, J. Vac. Sci. Technol. A, Sept./Oct. 1992, Pgs. 3048-3054, Vol.10, No. 5, American Vacuum Society.	
	C5	KOUZNETSOV, ET AL., A Novel Pulsed Magnetron Sputter Technique Utilizing Very High Target Power Densities, Surface & Coatings Technology, Pgs. 290-293, Elsevier Sciences S.A.	
	C6	LINDQUIST, ET AL., High Selectivity Plasma Etching Of Silicon Dioxide With A Dual Frequency 27/2 MHz Capacitive RF Discharge.	
	C7	MACAK, Reactive Sputter Deposition Process of Al2O3 and Characterization Of A Novel High Plasma Density Pulsed Magnetron Discharge, Linkoping Studies In Science And Technology, 1999, Pgs. 1-2, Sweden.	
	C8	MACAK, ET AL., Ionized Sputter Deposition Using An Extremely High Plasma Density Pulsed Magnetron Discharge, J. Vac Sci. Technol. A., July/August 2000, Pgs. 1533-37, Vol. 18, No. 4, American Vacuum Society	

Examiner	Date	
Signature	Considered	

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet	1	of	3

Complete if Known						
Application Number	10/065,551					
Filing Date	10/29/2002					
First Named Inventor	Chistyakov					
Art Unit	1765					
Examiner Name	Nguyen					
Attorney Docket Number	ZON-004					

	U.S. PATENT DOCUMENTS								
Examiner	Cito	Document Number	Publication Date	Name of Patentee or	Pages, Columns, Lines, Where				
		Number - Kind Code ² (<i>if known</i>		Applicant of Cited Document	Relevant Passages or Relevant Figures Appear				
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	FOREIGN PATENT DOCUMENTS									
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